

Electronic Supplementary Information (ESI)

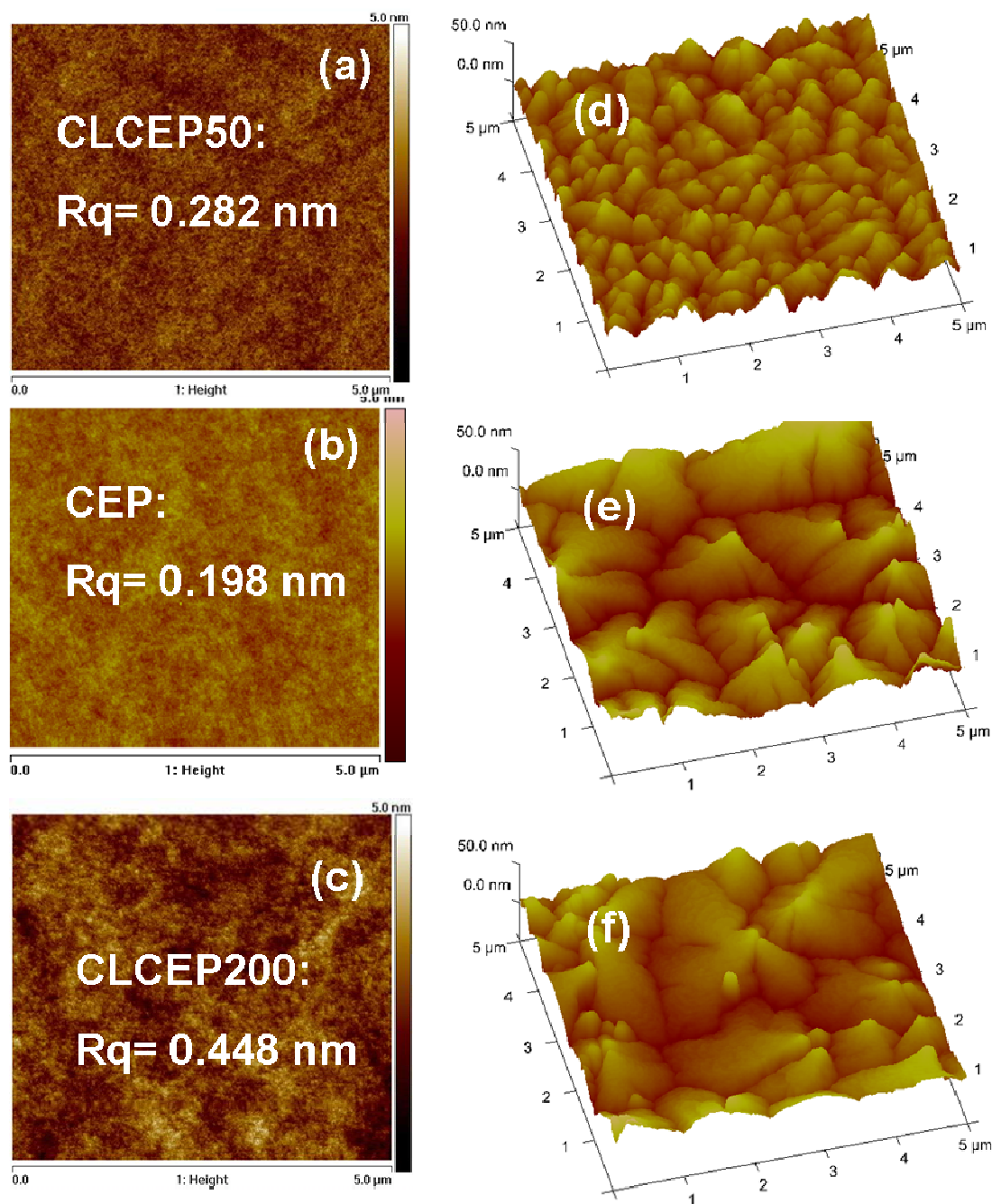


Figure A $5 \times 5 \mu\text{m}^2$ AFM images of dielectric surfaces (a) CLCEP50, (b) CEP and (c) CLCEP200, and 60 nm pentacene films grown on (d) CLCEP50, (e) CEP and (f) CLCEP200.

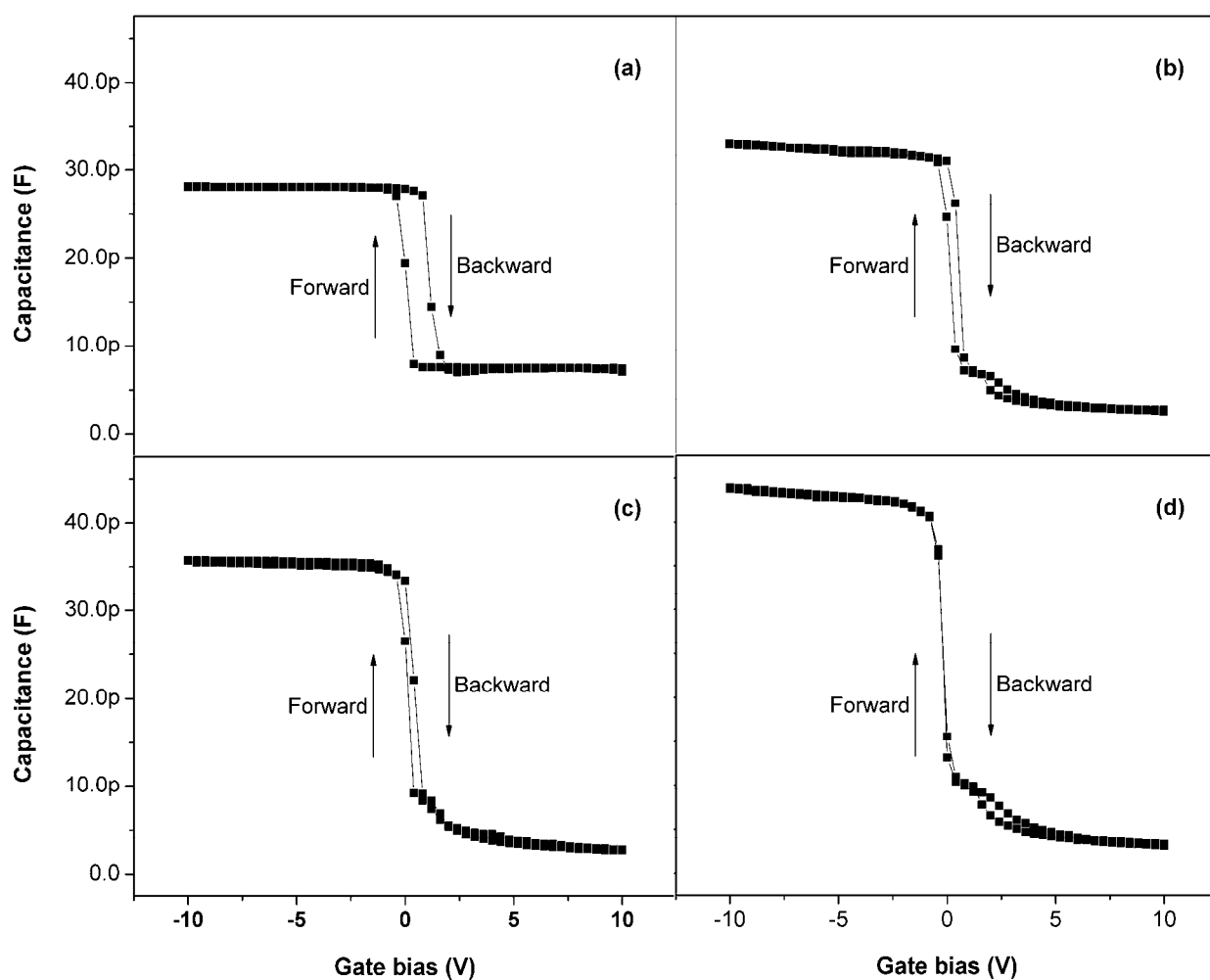


Figure B. Capacitance-voltage (C-V) characteristics of p-Si/CLCEP/Au MIS capacitors with (a) CLCEP50, (b) CLCEP100, (c) CLCEP150 and (d) CLCEP200 as a dielectric.